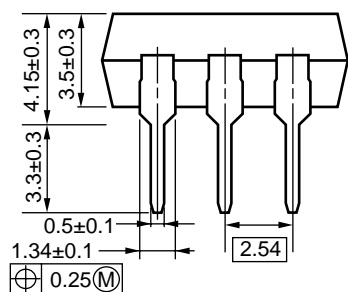
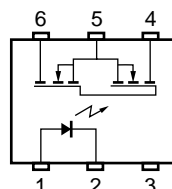


PS7141-1A



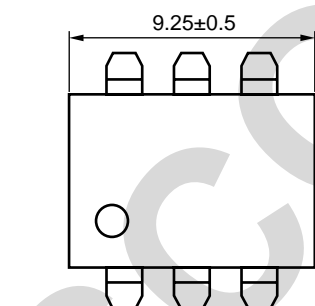
TOP VIEW



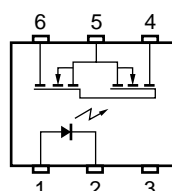
1. LED Anode
2. LED Cathode
3. NC
4. MOS FET Drain
5. MOS FET Source
6. MOS FET Drain



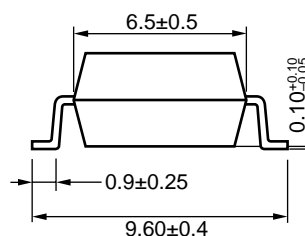
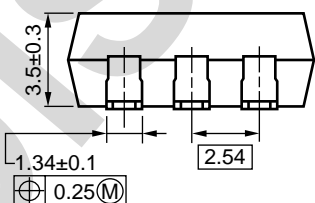
PS7141L-1A



TOP VIEW



1. LED Anode
2. LED Cathode
3. NC
4. MOS FET Drain
5. MOS FET Source
6. MOS FET Drain



ORDERING INFORMATION (Solder Contains Lead)

Part Number	Package	Packing Style	Application Part Number ^{*1}
PS7141-1A	6-pin DIP	Magazine case 50 pcs	PS7141-1A
PS7141L-1A			PS7141L-1A
PS7141L-1A-E3		Embossed Tape 1 000 pcs/reel	
PS7141L-1A-E4			

*1 For the application of the Safety Standard, following part number should be used.

ORDERING INFORMATION (Pb-Free)

Part Number	Package	Packing Style	Application Part Number ^{*1}
PS7141-1A-A	6-pin DIP	Magazine case 50 pcs	PS7141-1A
PS7141L-1A-A			PS7141L-1A
PS7141L-1A-E3-A		Embossed Tape 1 000 pcs/reel	
PS7141L-1A-E4-A			

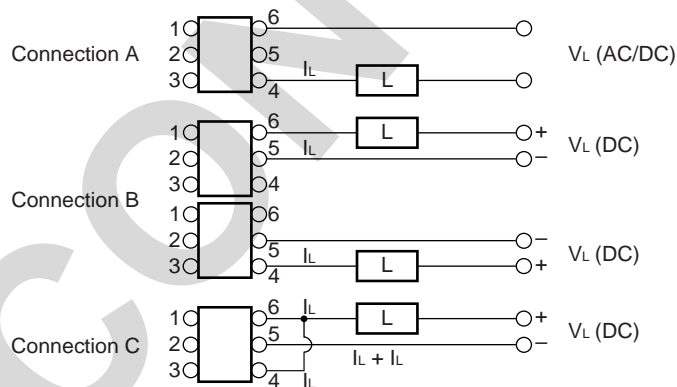
*1 For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

Parameter			Symbol	Ratings	Unit
Diode	Forward Current (DC)		I _F	50	mA
	Reverse Voltage		V _R	5.0	V
	Power Dissipation		P _D	50	mW
	Peak Forward Current * ¹		I _{FP}	1	A
MOS FET	Break Down Voltage		V _L	400	V
	Continuous Load Current * ²	Connection A	I _L	150	mA
		Connection B		200	
		Connection C		300	
	Pulse Load Current * ³ (AC/DC Connection)		I _{LP}	300	mA
	Power Dissipation		P _D	560	mW
Isolation Voltage * ⁴			BV	1 500	Vr.m.s.
Total Power Dissipation			P _T	610	mW
Operating Ambient Temperature			T _A	−40 to +85	°C
Storage Temperature			T _{stg}	−40 to +100	°C

*1 $PW = 100\text{ }\mu\text{s}$, Duty Cycle = 1 %

*2 Conditions: $I_F \geq 2\text{ mA}$. The following types of load connections are available.



*3 $PW = 100\text{ ms}$, 1 shot

*4 AC voltage for 1 minute at $T_A = 25\text{ }^{\circ}\text{C}$, RH = 60 % between input and output

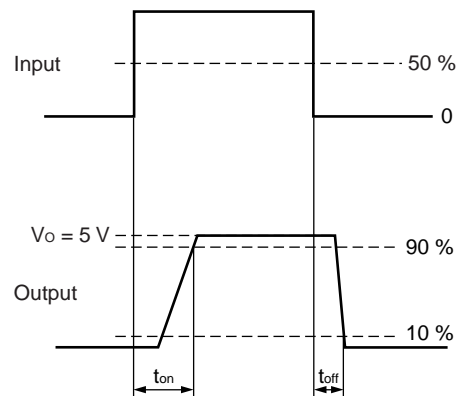
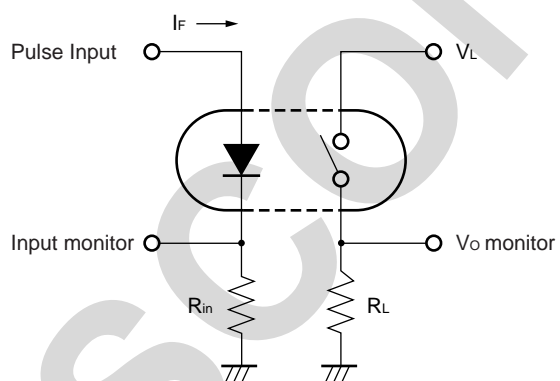
RECOMMENDED OPERATING CONDITIONS ($T_A = 25^\circ\text{C}$)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
LED Operating Current	I_F	2	10	20	mA
LED Off Voltage	V_F	0		0.5	V

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

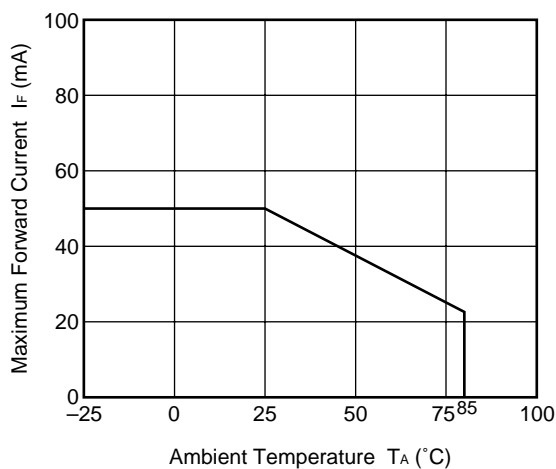
	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	V_F	$I_F = 10\text{ mA}$		1.2	1.4	V
	Reverse Current	I_R	$V_R = 5\text{ V}$			5.0	μA
MOS FET	Off-state Leakage Current	I_{Loff}	$V_D = 400\text{ V}$		0.03	1.0	μA
	Output Capacitance	C_{out}	$V_D = 0\text{ V}, f = 1\text{ MHz}$		65		pF
Coupled	LED On-state Current	I_{Fon}	$I_L = 150\text{ mA}$			2.0	mA
	On-state Resistance	R_{on1}	$I_F = 10\text{ mA}, I_L = 10\text{ mA}$		20	30	Ω
		R_{on2}	$I_F = 10\text{ mA}, I_L = 150\text{ mA}, t \leq 10\text{ ms}$		16	25	
	Turn-on Time *1	t_{on}	$I_F = 10\text{ mA}, V_O = 5\text{ V}, R_L = 1.5\text{ k}\Omega,$ $PW \geq 10\text{ ms}$		0.35	1.0	ms
	Turn-off Time *1	t_{off}			0.06	0.2	
	Isolation Resistance	$R_{\text{I-O}}$	$V_{\text{I-O}} = 1.0\text{ kV}_{\text{DC}}$	10^9			Ω
	Isolation Capacitance	$C_{\text{I-O}}$	$V = 0\text{ V}, f = 1\text{ MHz}$		1.1		pF

*1 Test Circuit for Switching Time

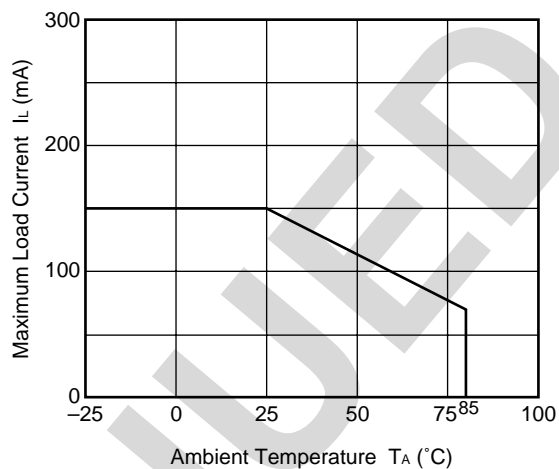


★ TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise specified)

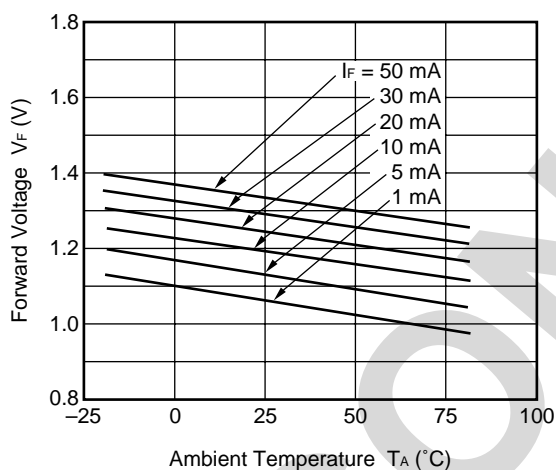
MAXIMUM FORWARD CURRENT vs.
AMBIENT TEMPERATURE



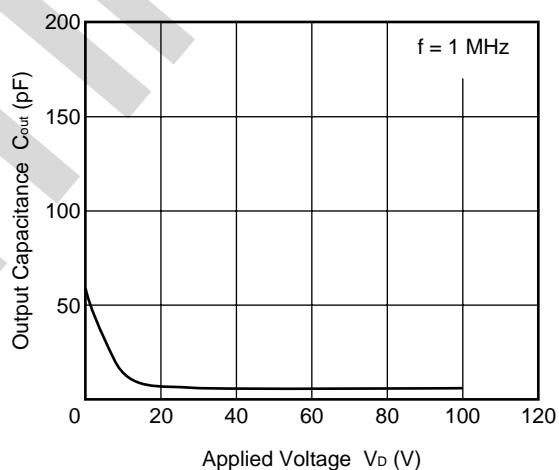
MAXIMUM LOAD CURRENT vs.
AMBIENT TEMPERATURE



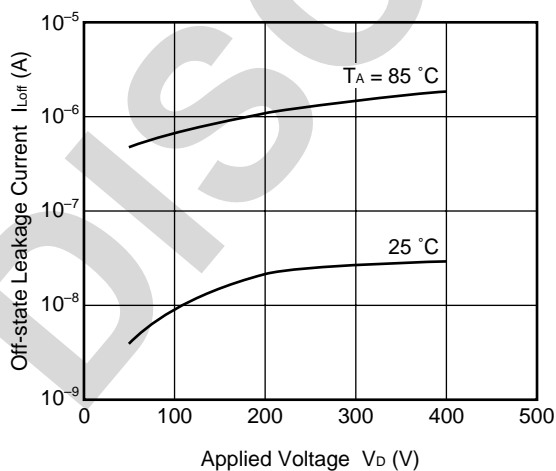
FORWARD VOLTAGE vs.
AMBIENT TEMPERATURE



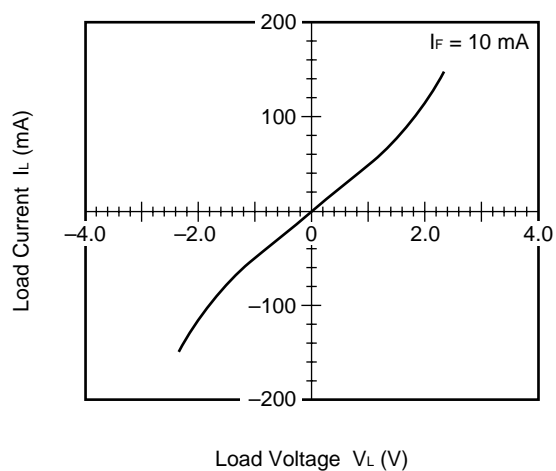
OUTPUT CAPACITANCE vs.
APPLIED VOLTAGE



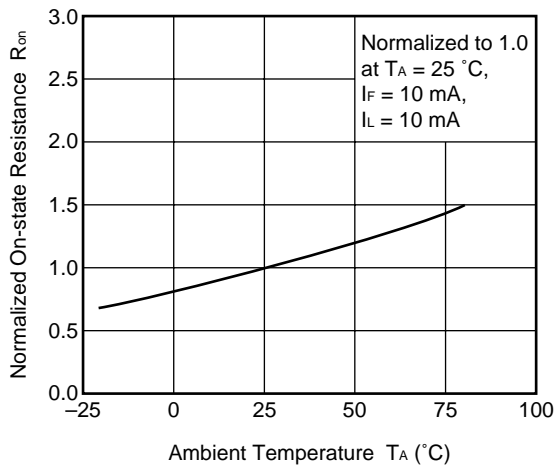
OFF-STATE LEAKAGE CURRENT vs.
APPLIED VOLTAGE



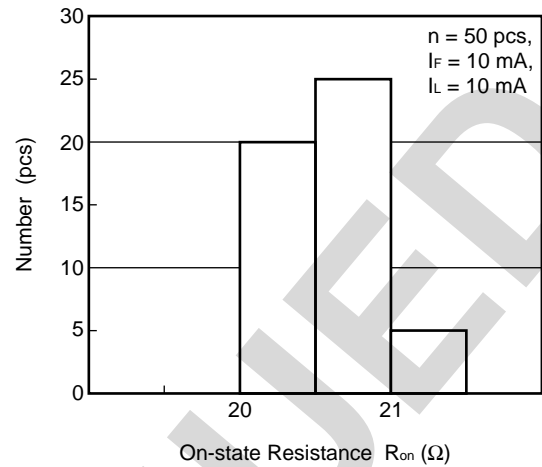
LOAD CURRENT vs. LOAD VOLTAGE



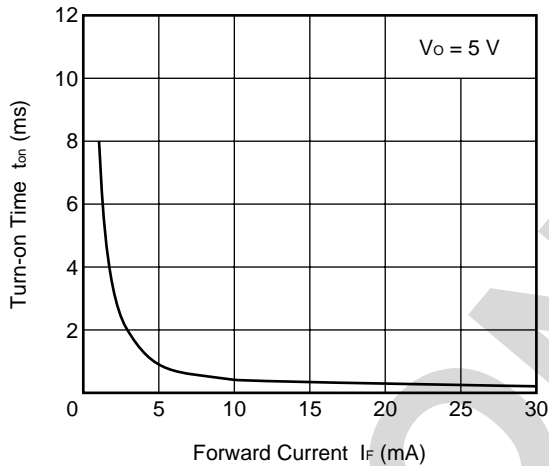
NORMALIZED ON-STATE RESISTANCE vs. AMBIENT TEMPERATURE



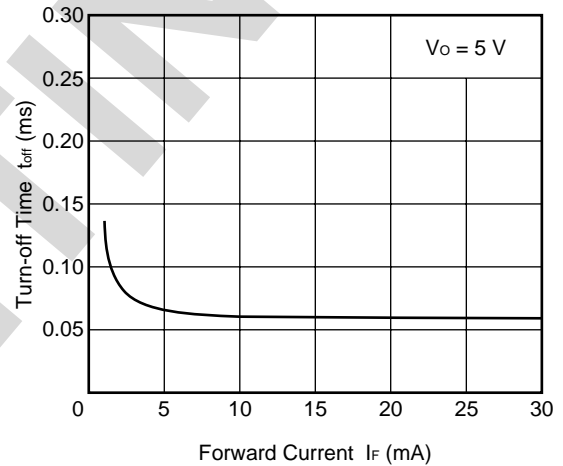
ON-STATE RESISTANCE DISTRIBUTION



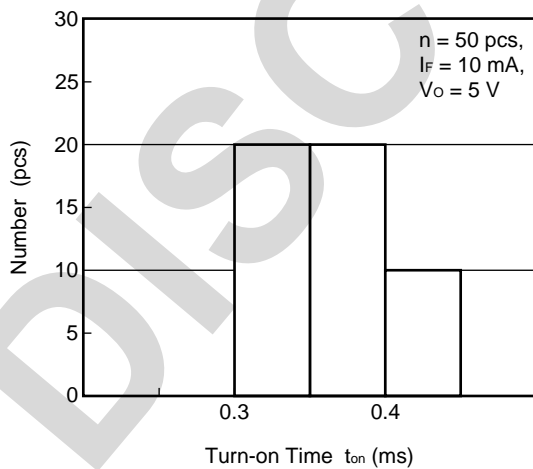
TURN-ON TIME vs. FORWARD CURRENT



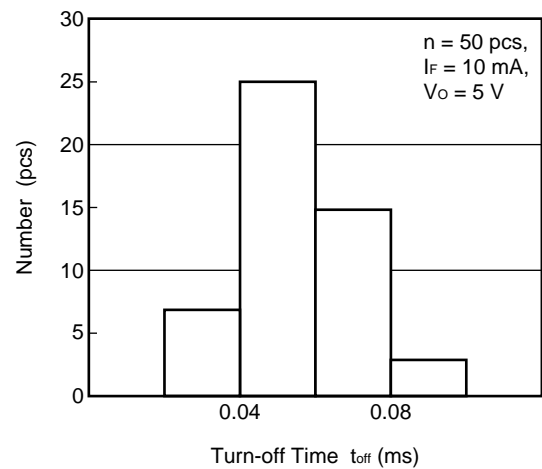
TURN-OFF TIME vs. FORWARD CURRENT



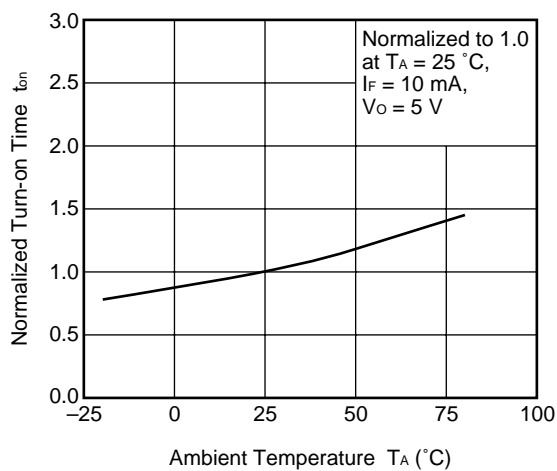
TURN-ON TIME DISTRIBUTION



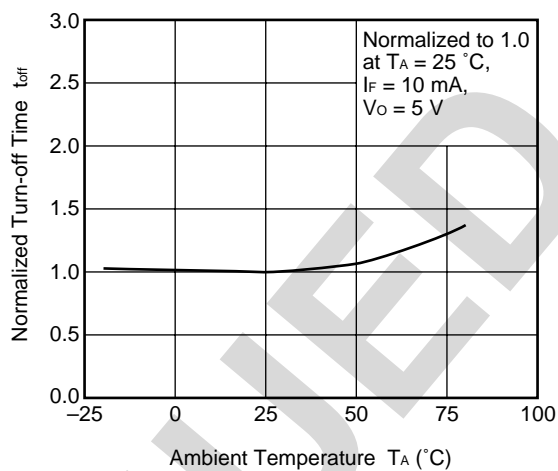
TURN-OFF TIME DISTRIBUTION



NORMALIZED TURN-ON TIME vs. AMBIENT TEMPERATURE



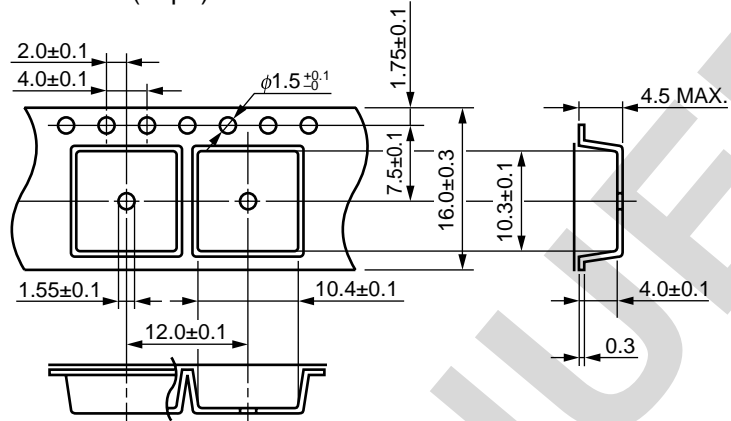
NORMALIZED TURN-OFF TIME vs. AMBIENT TEMPERATURE



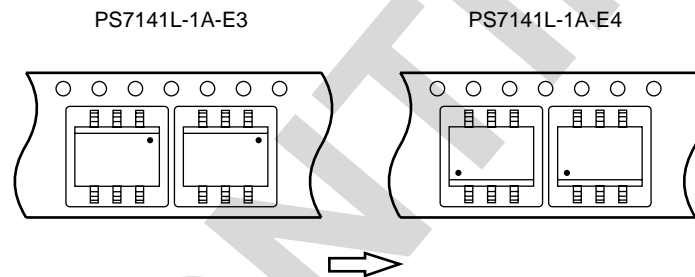
Remark The graphs indicate nominal characteristics.

★ TAPING SPECIFICATIONS (in millimeters)

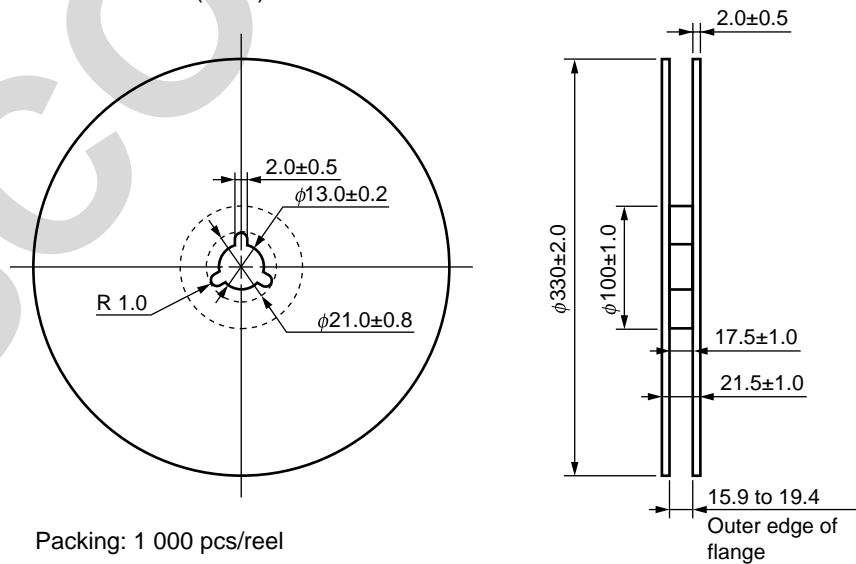
Outline and Dimensions (Tape)



Tape Direction



Outline and Dimensions (Reel)



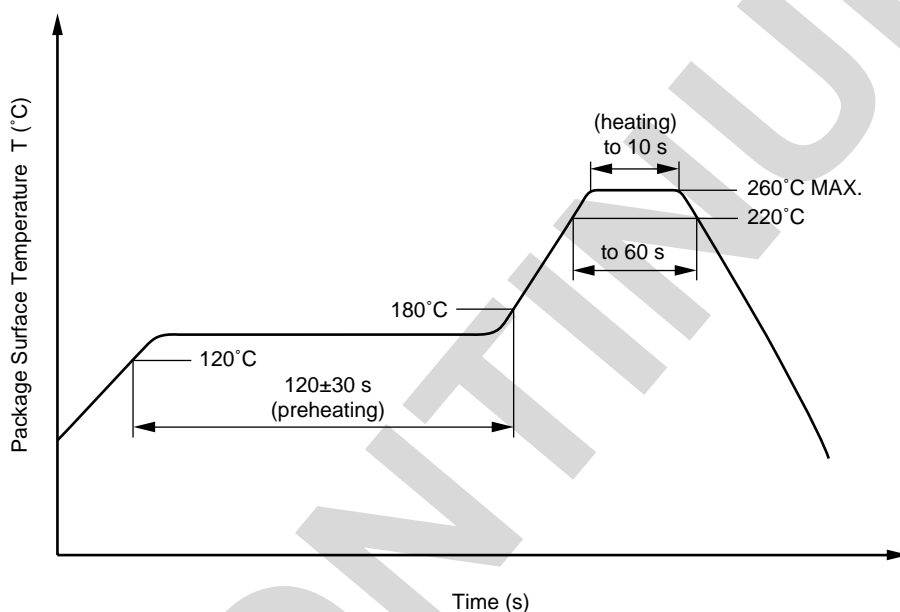
Packing: 1 000 pcs/reel

★ **RECOMMENDED SOLDERING CONDITIONS**

(1) Infrared reflow soldering

- | | |
|---|--|
| • Peak reflow temperature | 260°C or below (package surface temperature) |
| • Time of peak reflow temperature | 10 seconds or less |
| • Time of temperature higher than 220°C | 60 seconds or less |
| • Time to preheat temperature from 120 to 180°C | 120±30 s |
| • Number of reflows | Three |
| • Flux | Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.) |

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

- | | |
|-------------------------|--|
| • Temperature | 260°C or below (molten solder temperature) |
| • Time | 10 seconds or less |
| • Preheating conditions | 120°C or below (package surface temperature) |
| • Number of times | One |
| • Flux | Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.) |

(3) Cautions

- Fluxes
 - Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices	
		-A	-AZ
Lead (Pb)	< 1000 PPM	Not Detected	(*)
Mercury	< 1000 PPM	Not Detected	
Cadmium	< 100 PPM	Not Detected	
Hexavalent Chromium	< 1000 PPM	Not Detected	
PBB	< 1000 PPM	Not Detected	
PBDE	< 1000 PPM	Not Detected	

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

Important Information and Disclaimer: Information provided by CEL on its website or in other communications concerning the substance content of its products represents knowledge and belief as of the date that it is provided. CEL bases its knowledge and belief on information provided by third parties and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. CEL has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. CEL and CEL suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall CEL's liability arising out of such information exceed the total purchase price of the CEL part(s) at issue sold by CEL to customer on an annual basis.

See CEL Terms and Conditions for additional clarification of warranties and liability.